NSN 5961-01-331-4812



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-331-4812 **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-18 **Mounting Method: Terminal Terminal Circle Diameter:** Between 0.016 inches and 0.021 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 0.75 limiting voltage and 1.75 limiting voltage **Current Rating Per Characteristic:** 1.80 milliamperes forward current, dc and 50.00 milliamperes reverse current, dc **Power Rating Per Characteristic:** 1.25 watts total device dissipation **Capacitance Rating In Picofarads:** 6.0 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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